INTERNATIONAL SEARCH REPORT

Intern | Application No PCT/GB2005/000258

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tional application No.

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Box No. IV Text of the abstract (Continuation of item 5 of the first sheet)

This invention generally relates to improved structures for organic light emitti ng diodes (OLEDs), and more particularly to so-called top emitting OLEDs. An org anic light emitting diode (OLED) 300 comprising a substrate 102 bearing a Tight emitting layer 108a, between an electrically conducting anode 106 and an electr ically conducting mathode 200, the diode baing configured for Tight emission thr ough said cathode, the cathode being transmissive at a light emission wavelength of the dicde, and wherein said cathods incorporates an optical interference str ucture 202, 204, 206 configured to enhance light transmission through said catho de at said emission wavelength.